國立成功大學八十二學年度 正設所 考試(設計方法 試題) 其 1 頁

In a design of a series of new products shown in Figure 1, assume that you are the major designer who is responsible for this design project, discuss the following questions:

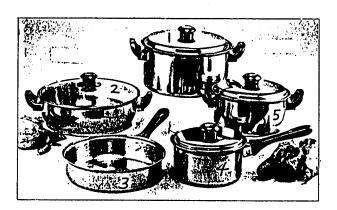


Figure 1. Five New Designs of Pots and Pans

- (10 %) 1. Specify your design goals, design objectives, and design criteria.
- (10 %) 2. In order to determine your design criteria for this design project, explain how you deal with the analysis of product needs.
- (10 %) 3. Develop product structures for these pots and pans.
- (10 %) 4. Use morphological analysis to generate design alternatives that are based on product structures you developed in Question 3.
- (10 %) 5. Develop a design process to determine feasible design alternatives and the optimum feasible design alternative for the generated design alternatives that you did in Question 4.

Notes:

- 1. In answering each question, you should keep your statements, interpretation, or discussion be directly towarded to the above design project. Do'nt use any general concepts for your answers; otherwise, you will not gain any credit.
- You may use tables, figures, drawings, or any representation technique as parts of your answers.
- 3. In question 5, you should consider what kinds of theories, rules, concepts, approaches, or problem solving techniques can be efficiently and appropriately applied in the steps of your design process. Do'nt just mention a general purpose design process. This design process should also be based on this design project.

國立成功大學人十二學年度工設所考試(設計方法 試題)并 頁一. 在建立形態分析(Morphological Approach)表《如下圖》,参數的設定。要

多数 (Parameters)	爱昊可式 (Variations)					
A	A1 A2 A3 A4					
В	β, β2					
C	C1 C2 C3					

注意那些原则?就引攀六個。(15%)

二. 請自行學-個是例——設計主題(Subject),並用系统定義矩阵(System Definition Matrix ,由七個系統元件及近個何度所構成之紀律,如下圖) 之順序乌龙各章纸上。(註,名析攀之矣何)——该计主起,必须非常清楚的描述在为,然後再当A1,……至2的各集)(35%)

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